Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 120 A



- Two fully independent diodes
- Ceramic fully insulated package (V_{ISOL} = 2500 V_{AC})
- Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape
- Low forward voltage
- Optimized for power conversion: welding and industrial SMPS applications
- Industry standard outline
- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- Direct mounting to heatsink
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

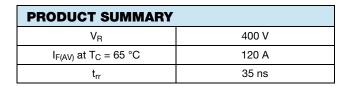
The UFB120FA40P insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, dc-to-dc converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
Continuous forward current per diode	١ _F	T _C = 65 °C	60	А	
Single pulse forward current per diode	I _{FSM}	T _C = 25 °C	800		
Maximum power dissipation per module	PD	T _C = 90 °C	96	W	
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 minute	2500	V	
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 150 °C	°C	

For technical questions within your region, please contact one of the following:

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Document Number: 94086

Revision: 21-Jul-10







COMPLIANT





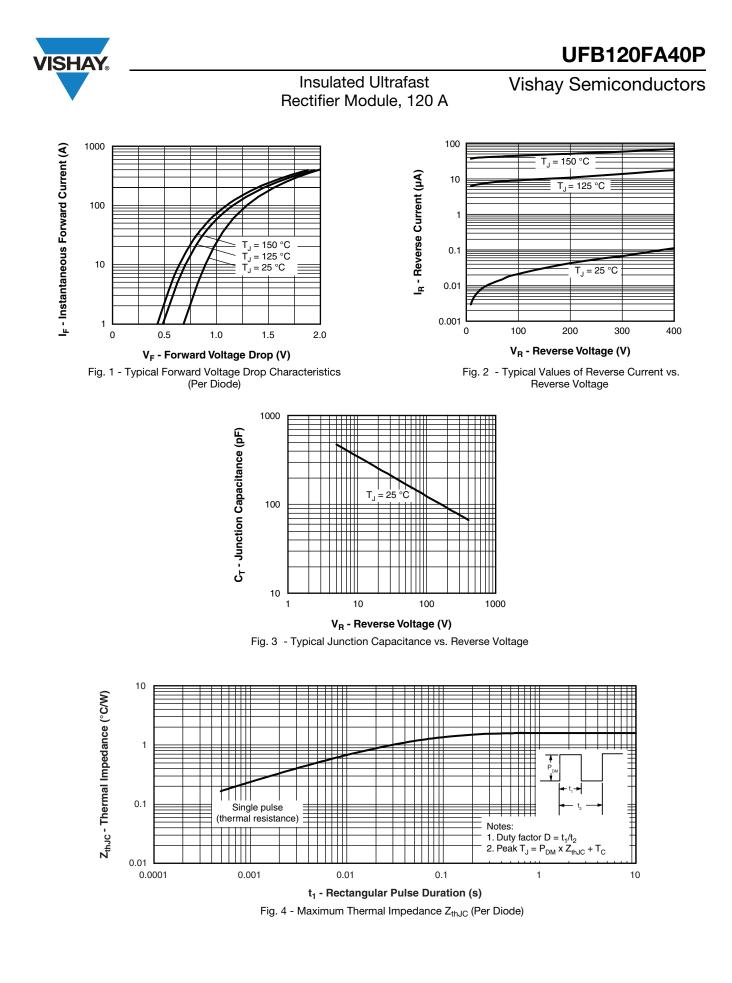
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ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	400	-	-	
Forward voltage	V	I _F = 60 A	-	1.16	1.37	V
	V _{FM}	I _F = 60 A, T _J = 150 °C	-	0.96	1.13	
Reverse leakage current	la c	$V_{R} = V_{R}$ rated	-	-	0.1	mA
	I _{RM}	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1	IIIA
Junction capacitance	CT	V _R = 400 V	-	67	-	pF

DYNAMIC RECOVERY CHARACTERISTICS PER DIODE (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	30	35	
Reverse recovery time t _{rr}	t _{rr}	T _J = 25 °C		-	65	-	ns
		T _J = 125 °C	I _F = 50 A dI _F /dt = 200 A/μs V _R = 200 V	-	128	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	7.4	-	A
		T _J = 125 °C		-	17.8	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	240	-	nC
		T _J = 125 °C		-	1139	-	

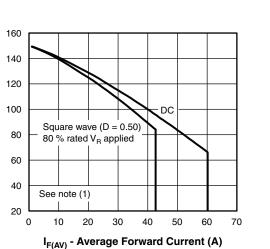
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single diode conducting	Р		-	0.99	1.24	
Junction to case, both diodes conducting	R _{thJC}		-	0.49	0.62	°C/W
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm

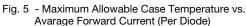


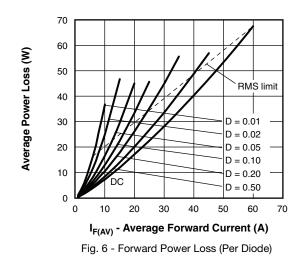
Allowable Case Temperature (°C)

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Note

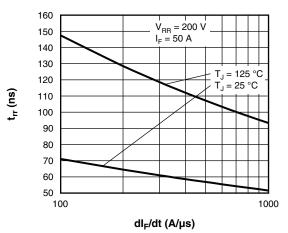


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

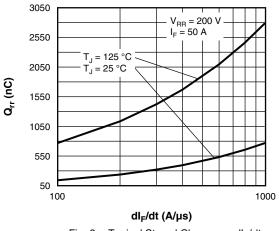


Fig. 8 - Typical Stored Charge vs. dl_F/dt



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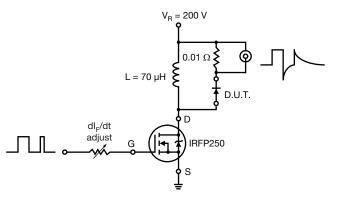
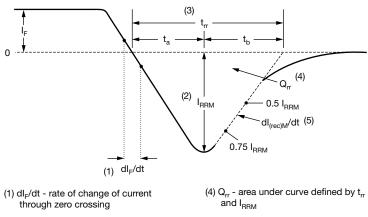


Fig. 9 - Reverse Recovery Parameter Test Circuit



(2) I_{RRM} - peak reverse recovery current

- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

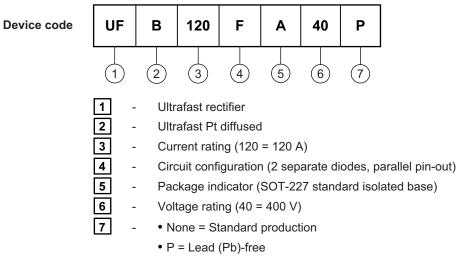
Fig. 10 - Reverse Recovery Waveform and Definitions

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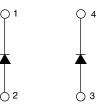
ORDERING INFORMATION TABLE

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Quantity per tube is 10, M4 screw and washer included

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95036				
Packaging information	www.vishay.com/doc?95037				

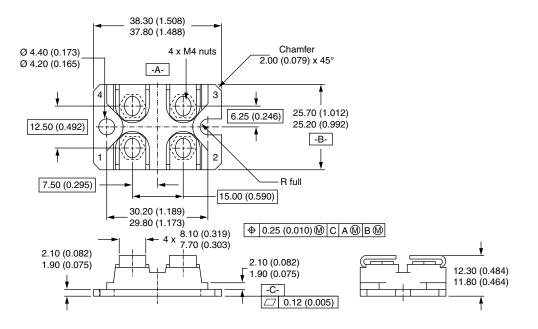


Outline Dimensions

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SOT-227

DIMENSIONS in millimeters (inches)



Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter



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